

Vishay Siliconix

## Dual P-Channel 30-V (D-S) MOSFET

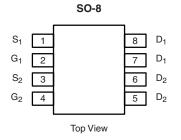
PRODUCT SUMMARY					
V <sub>DS</sub> (V)	R <sub>DS(on)</sub> (Ω)	I <sub>D</sub> (A)			
- 30	0.025 at V <sub>GS</sub> = - 10 V	- 7.1			
	0.041 at V <sub>GS</sub> = - 4.5 V	- 5.5			

#### FEATURES

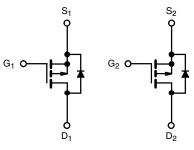
- Halogen-free According to IEC 61249-2-21
  Definition
- TrenchFET<sup>®</sup> Power MOSFET
- Compliant to RoHS Directive 2002/95/EC

#### **APPLICATIONS**

- Load Switches
  - Notebook PCs
  - Desktop PCs
  - Game Stations



Ordering Information: Si4925BDY-T1-E3 (Lead (Pb)-free) Si4925BDY-T1-GE3 (Lead (Pb)-free and Halogen-free)



P-Channel MOSFET P-Channel MOSFET

<b>ABSOLUTE MAXIMUM RATINGS</b> $T_A = 25 \degree C$ , unless otherwise noted						
Parameter		Symbol	10 s	Steady State	Unit	
Drain-Source Voltage		V <sub>DS</sub>	- 30		V	
Gate-Source Voltage		V <sub>GS</sub>	± 20			
	T <sub>A</sub> = 25 °C	- I <sub>D</sub> -	- 7.1	- 5.3		
Continuous Drain Current (T <sub>J</sub> = 150 °C) <sup>a</sup>	T <sub>A</sub> = 70 °C		- 5.7	- 4.3	•	
Pulsed Drain Current		I <sub>DM</sub>	- 40		A	
Continuous Source Current (Diode Conduction) <sup>a</sup>		۱ <sub>S</sub>	- 1.7	- 0.9		
	T <sub>A</sub> = 25 °C	- P <sub>D</sub>	2.0	1.1	W	
Maximum Power Dissipation <sup>a</sup>	T <sub>A</sub> = 70 °C		1.3	0.7	vv	
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150		°C	

THERMAL RESISTANCE RATINGS						
Parameter	Symbol	Typical	Maximum	Unit		
	t ≤ 10 s	R <sub>thJA</sub>	50	62.5		
Maximum Junction-to-Ambient <sup>a</sup>	Steady State		85	110	°C/W	
Maximum Junction-to-Foot (Drain)	Steady State	R <sub>thJF</sub>	30	40		

Notes:

a. Surface Mounted on 1" x 1" FR4 board.



HALOGEN

Available

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ons	Min.	Тур.	Max.	Unit			
· 250 μA	- 1		- 3	V			
= ± 20 V			± 100	nA			

Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_{D} = -250 \ \mu A$	- 1		- 3	V	
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA	
Zarra Oata Maltana Drain Ourrant		$V_{DS} = -30 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			- 1		
Zero Gate Voltage Drain Current	IDSS	$V_{DS}$ = - 30 V, $V_{GS}$ = 0 V, $T_{J}$ = 55 °C	- 25		- 25	μΑ	
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} = -5 V, V_{GS} = -10 V$	- 40			Α	
	R <sub>DS(on)</sub>	V <sub>GS</sub> = - 10 V, I <sub>D</sub> = - 7.1 A	0.020		0.025	0	
Drain-Source On-State Resistance <sup>a</sup>		V <sub>GS</sub> = - 4.5 V, I <sub>D</sub> = - 5.5 A		0.033	0.041	Ω	
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	V <sub>DS</sub> = - 10 V, I <sub>D</sub> = - 7.1 A		20		S	
Diode Forward Voltage <sup>a</sup>	V <sub>SD</sub>	I <sub>S</sub> = - 1.7 A, V <sub>GS</sub> = 0 V		- 0.8	- 1.2	V	
Dynamic <sup>b</sup>				•			
Total Gate Charge	Qg			33	50		
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}$ = - 15 V, $V_{GS}$ = - 10 V, $I_{D}$ = - 7.1 A		5.4		nC	
Gate-Drain Charge	Q <sub>gd</sub>			8.9			
Turn-On Delay Time	t <sub>d(on)</sub>			9	15		
Rise Time	t <sub>r</sub>	$V_{DD}$ = - 15 V, $R_L$ = 15 $\Omega$		12	20	ns	
Turn-Off Delay Time	t <sub>d(off)</sub>	$\text{I}_\text{D}\cong$ - 1 A, $\text{V}_\text{GEN}$ = - 10 V, $\text{R}_\text{g}$ = 6 $\Omega$		60	90		
Fall Time	t <sub>f</sub>			34	50		
Source-Drain Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = - 1.7 A, dl/dt = 100 A/μs		30	60		

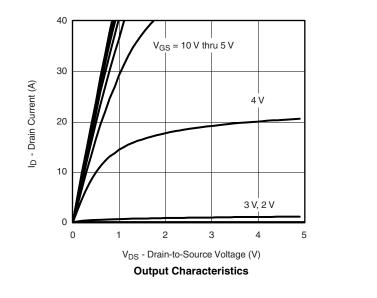
Notes:

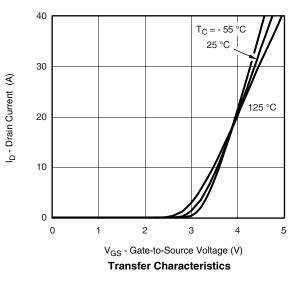
a. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %.

b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

#### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



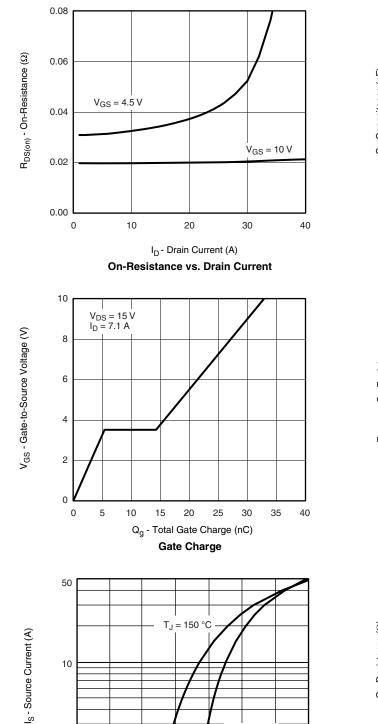


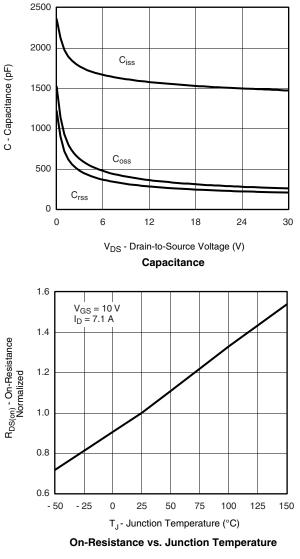


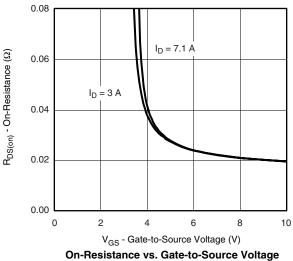
## Si4925BDY

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#### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted







1 L

0.2

0.4

0.6

V<sub>SD</sub> - Source-to-Drain Voltage (V)

Source-Drain Diode Forward Voltage

0.8

T<sub>J</sub> = 25 °C

1.0

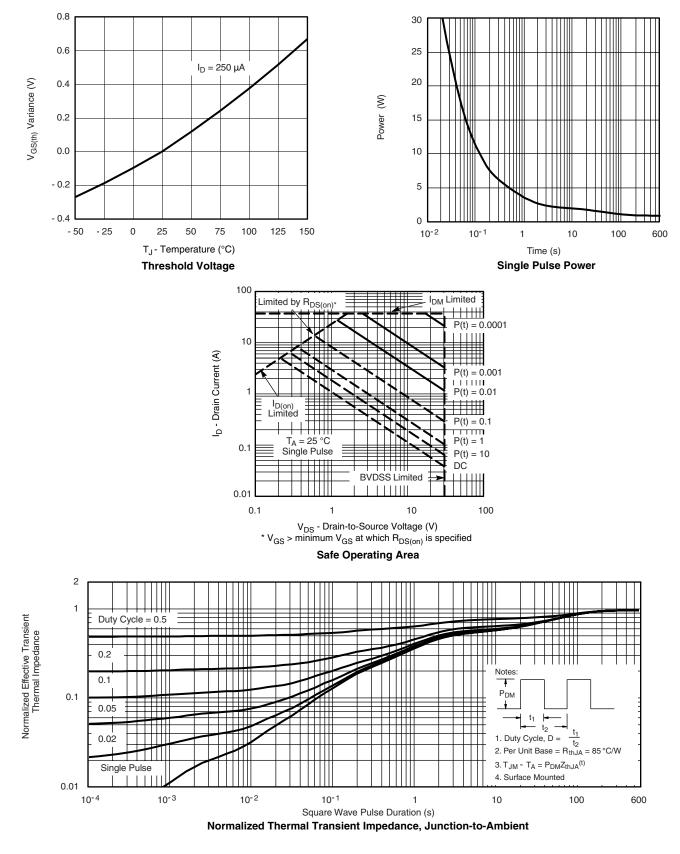
1.2

1.4

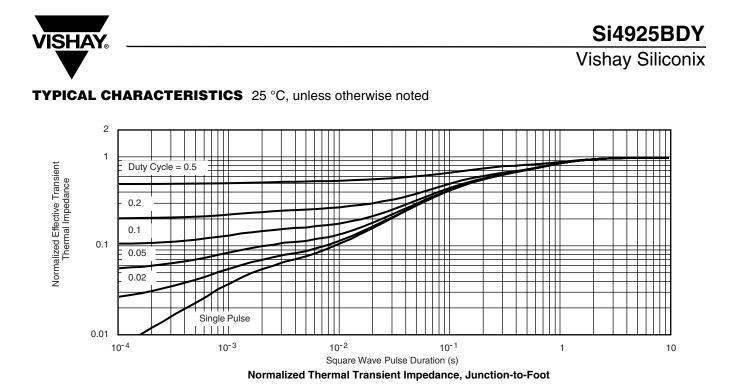
## Si4925BDY

### **Vishay Siliconix**





/ISHA



Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see <a href="http://www.vishay.com/ppg772001">www.vishay.com/ppg772001</a>.



# Package Information

Vishay Siliconix

#### SOIC (NARROW): 8-LEAD

JEDEC Part Number: MS-012





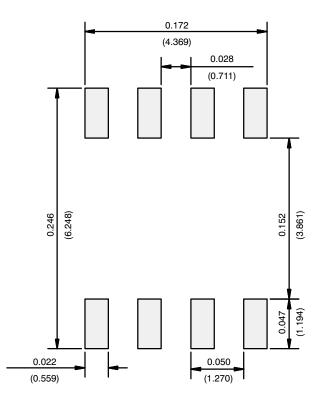
	MILLIM	IETERS	INCHES			
DIM	Min	Мах	Min	Max		
A	1.35	1.75	0.053	0.069		
A <sub>1</sub>	0.10	0.20	0.004	0.008		
В	0.35	0.51	0.014	0.020		
С	0.19	0.25	0.0075	0.010		
D	4.80	5.00	0.189	0.196		
E	3.80	4.00	0.150	0.157		
е	1.27	BSC	0.050 BSC			
н	5.80	6.20	0.228	0.244		
h	0.25	0.50	0.010	0.020		
L	0.50	0.93	0.020	0.037		
q	0°	8°	0°	8°		
S	0.44	0.64	0.018	0.026		
ECN: C-06527-Rev. I, 11-Sep-06 DWG: 5498						

# **Application Note 826**

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**RECOMMENDED MINIMUM PADS FOR SO-8** 



Recommended Minimum Pads Dimensions in Inches/(mm)

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